

(High Purity Polycrystalline Silicon)

가
(Trichlorosilane, SiCl₃)

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(: M/T, 100)				
	1991	1992	1993	1994
	7,800	9,700	10,000	10,850
	351	437	450	489
	4,134	5,140	5,300	5,750
	1,240	1,542	1,590	1,725
Wafer	1,782	1,889	2,059	2,306
	2,090	2,215	2,414	2,700

(: M/T, 100)								
	1990	1991	1992	1993	1994	1995	1996	1997
	647	666	742	836	930	1,053	1,208	1,387
	29	30	33	38	42	47	54	62
	343	353	393	443	493	558	640	735
	103	106	118	133	148	167	192	221
Wafer(MSI/)	137	141	157	177	197	223	256	294
	154	158	176	203	227	250	287	330

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93 1 4 5000 800 3800
2000 1500
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